

AMENDMENTS TO THE SPECIFICATION:

Please replace the title with the following amended title:

~~INSULATED GATE~~ NEW SELF-ALIGNED PRODUCTION METHOD FOR AN
INSULATED GATE SEMICONDUCTOR DEVICE CELL ~~AND METHOD OF~~
~~MAKING THE SAME~~ INSULATED GATE SEMICONDUCTOR DEVICE CELL

Please insert the following paragraph before line 2 on page 1 of the above-identified specification.

Related applications

This application claims priorities under 35 U.S.C. §119 to European Application No. 02406086.5 filed December 10, 2002, and Under 35 U.S.C. §371 to PCT Application No. PCT/CH2003/000809 filed as an International Application on December 9, 2003 designating the U.S., the entire contents of which are hereby incorporated by reference in their entireties.